

Investigation of temperature switching stability of AlGaAs/GaAs-based high-voltage subnanosecond optothyristor switch

Korolkov, V.I.; Rozhkov, A.V.; Zhuravleva, V.V.; Orlov, N.Yu.; Petropavlovskay, I.A.; Soldatenkov, F.Yu. BEC : Baltic Electronics Conference : proceedings of the 4th Biennial Conference, October 9-14, 1994, Tallinn (Estonia). 2 1994 / p. 545-551: ill

Numerical calculations of transient characteristics of a vertical field effect phototransistor taking into account resistance on the gate

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